

### Device Features

- OIP3 = 41.0 dBm @ 1900 MHz
- Gain = 15.5 dB @ 1900 MHz
- Output P1 dB = 25.5 dBm @ 1900 MHz
- RoHS2-compliant SOT-89 SMT package



### Product Description

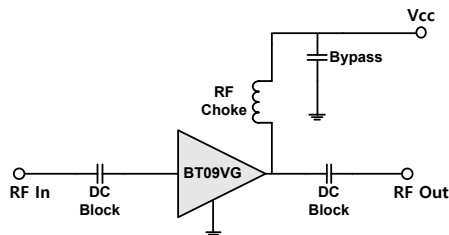
BeRex's BT09VG is a high performance and a high dynamic range amplifier in a low cost surface mount package(SOT-89) with a RoHS2-compliant, that incorporates reliable heterojunction-bipolar-transistor (HBT) devices fabricated with InGaP GaAs technology. This device is designed for use where high linearity is required and features high OIP3 and P1 with low consumption current(85mA) and requires a few external matching components such as a DC blocking capacitors on the In/Output pin, a bypass capacitor and a RF choke for the out port.

All devices are 100% RF/DC tested.

### Applications

- Base station Infrastructure/RFID
- Commercial/Industrial/Military wireless system
- Wireless LAN

### Application Circuits



\*External matching circuit: refer to the page 5 to 14.

### Electrical Specifications

Device performance \_ measured on a BeRex evaluation board at 25°C, Vc=5V, 50 Ω system.

Parameter	Conditions	Min	Typ	Max	Unit
Operational Frequency Range		5		4000	MHz
Test Frequency			1900		MHz
Gain		14.0	15.5		dB
Input Return Loss			-30.0		dB
Output Return Loss			-19.0		dB
Output IP3	13 dBm/tone, Δf=1 MHz	38.0	41.0		dBm
Output P1dB		23.5	25.5		dBm
Noise Figure			4.0		dB

### Recommended Operating Conditions

Parameter	Min	Typ	Max	Unit
Bandwidth	5		4000	MHz
I <sub>C</sub> @ (V <sub>c</sub> = 5V)	130	160	190	mA
V <sub>c</sub>	4.75	5.0	5.25	V
R <sub>TH</sub>		50		°C/W
Operating Case Temperature	-40		+85	°C

Electrical specifications are measured at specified test conditions.

Specifications are not guaranteed over all recommended operating conditions.

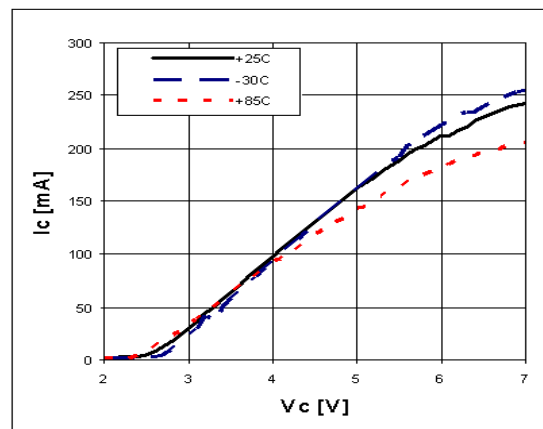
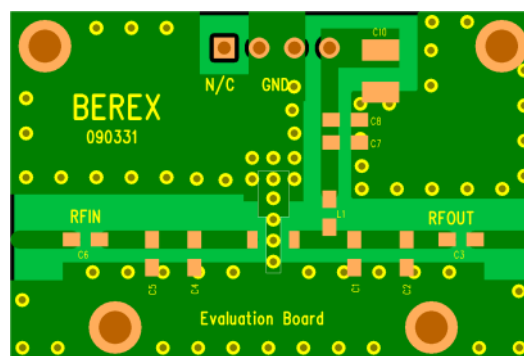
### Absolute Maximum Ratings

Parameter	Rating	Unit
Storage Temperature	-55 to +155	°C
Junction Temperature	+190	°C
Supply Voltage	+7.0	V
Supply Current	220	mA
Input RF Power	23	dBm

\*Operation of this device above any of these parameters may result in permanent damage.

**Typical Performance (Vc=5V, Ic=160mA, T=25°C)**

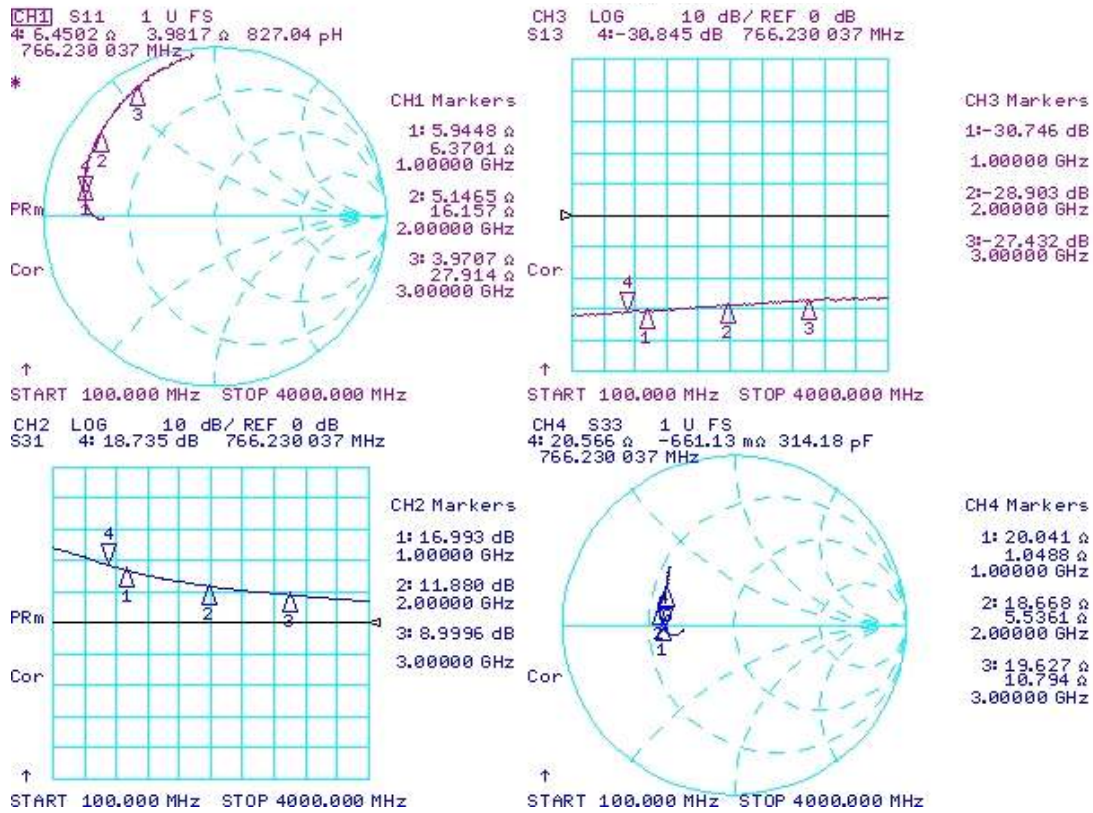
Parameter	Frequency				Unit
	900	1900	2450	3500	
Gain	21.5	15.5	13.5	10.8	dB
S11	-16.0	-30.0	-14.0	-15.0	dB
S22	-24.0	-19.0	-19.0	-14.0	dB
OIP3	39.0	41.0	41.0	42.0	dBm
P1dB	24.5	25.5	27.0	25.0	dBm
Noise Figure	3.7	4.0	4.7	5.4	dB

**V-I Characteristics**

**BeRex SOT89 Evaluation Board**


\*Dielectric constant \_ 4.2 \*RF pattern width 52mil \*31mil thick FR4 PCB

### Typical Device Data

S-parameters (Vc=5V, Ic=160mA, T=25°C)

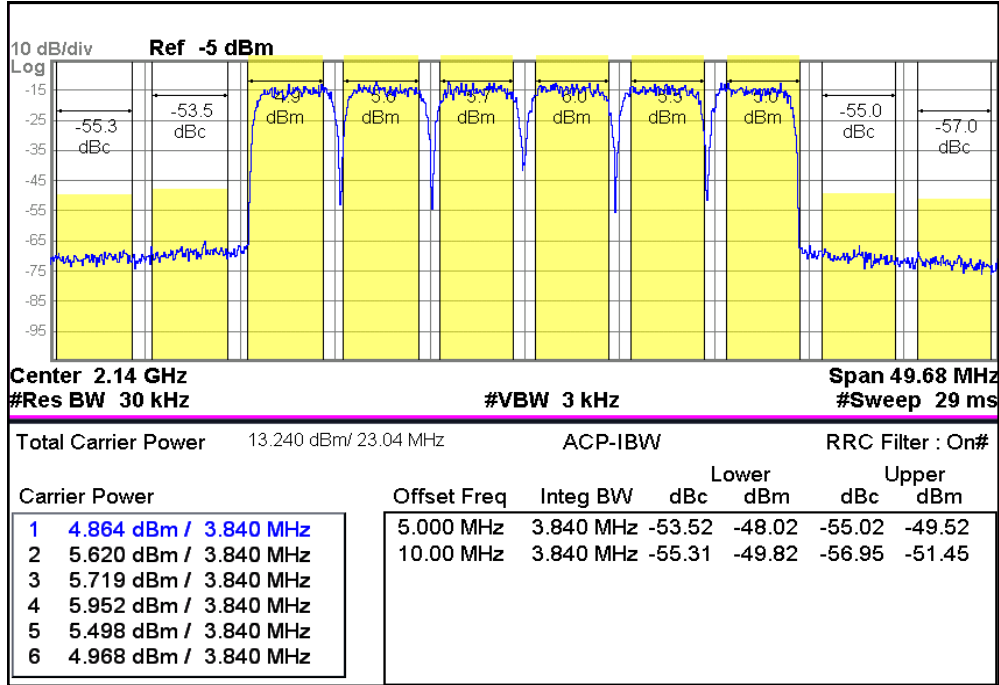


### S-Parameter

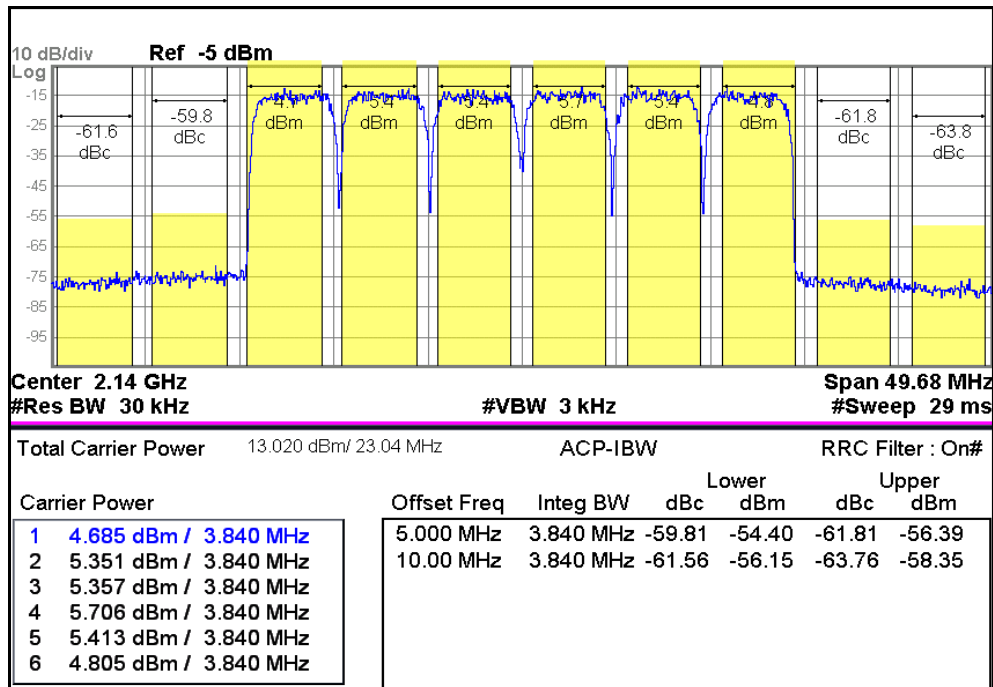
(Vdevice = 5.0V, Icc = 160mA, T = 25 °C, calibrated to device leads)

Freq [MHz]	S11		S21		S12		S22	
	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
100	0.65	-180.00	16.00	170.00	0.03	2.50	0.30	-170.00
500	0.74	180.00	11.00	130.00	0.03	8.90	0.38	-170.00
1000	0.79	170.00	7.00	98.00	0.03	14.00	0.42	180.00
1500	0.81	150.00	5.00	82.00	0.03	18.00	0.44	170.00
2000	0.83	140.00	3.90	69.00	0.04	19.00	0.46	170.00
2500	0.85	130.00	3.20	57.00	0.04	19.00	0.45	160.00
3000	0.88	120.00	2.80	46.00	0.04	18.00	0.45	150.00
3500	0.92	110.00	2.50	35.00	0.04	14.00	0.48	140.00
4000	0.96	98.00	2.20	23.00	0.05	11.00	0.51	140.00

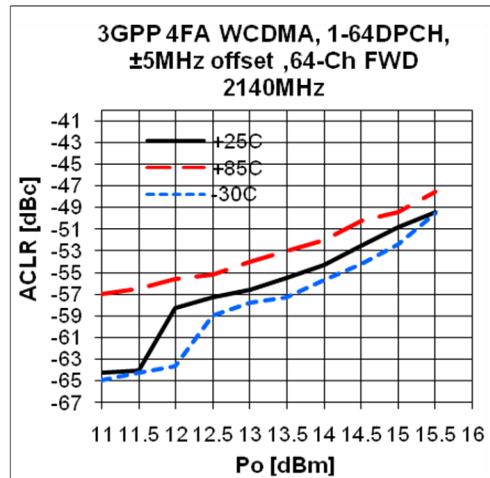
### WCDMA 6FA 2140 -55dBc



### WCDMA 6FA 2140 -60dBc



### ACLR

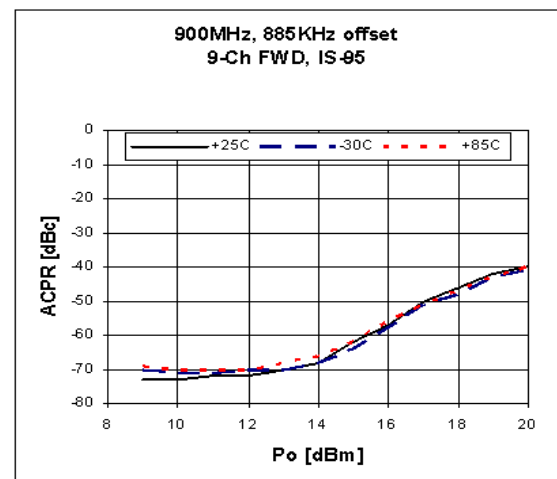
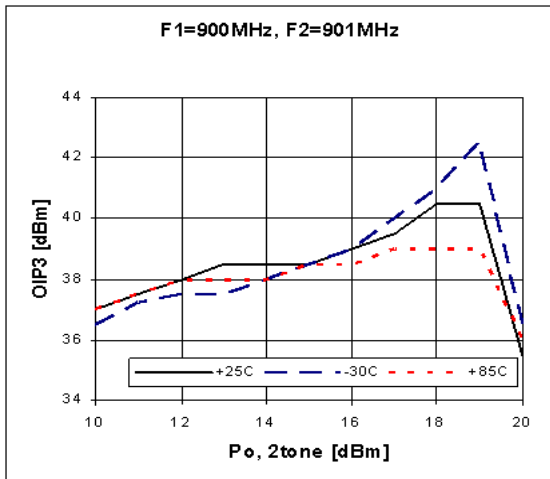
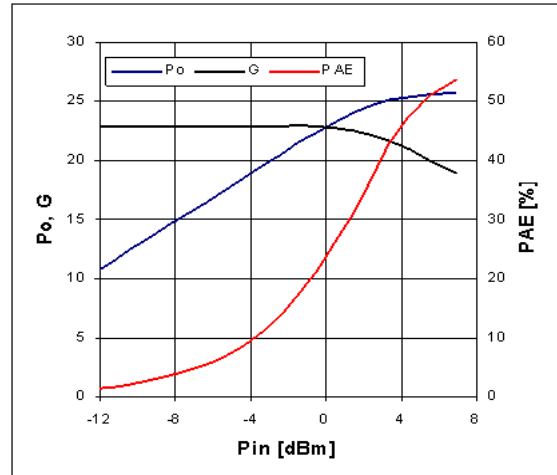
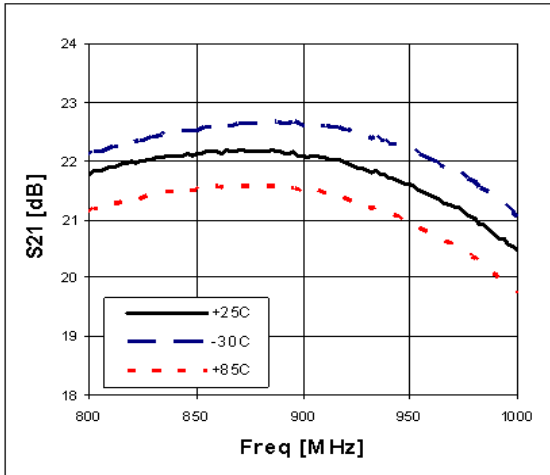
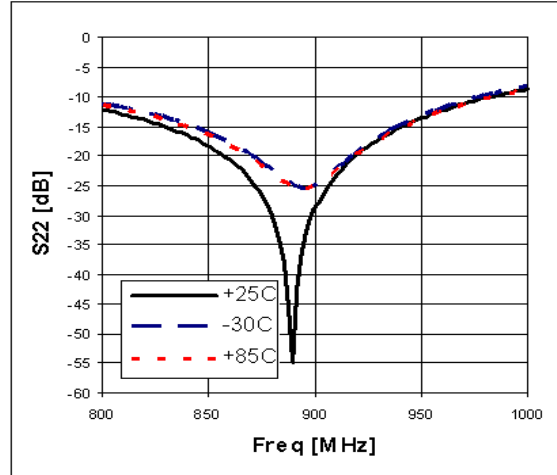
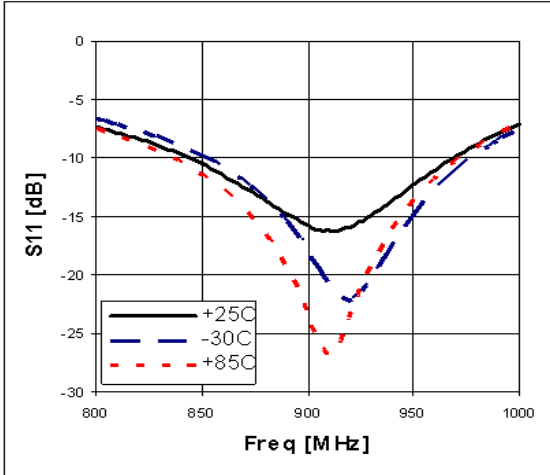


### Application Circuit: 900 MHz

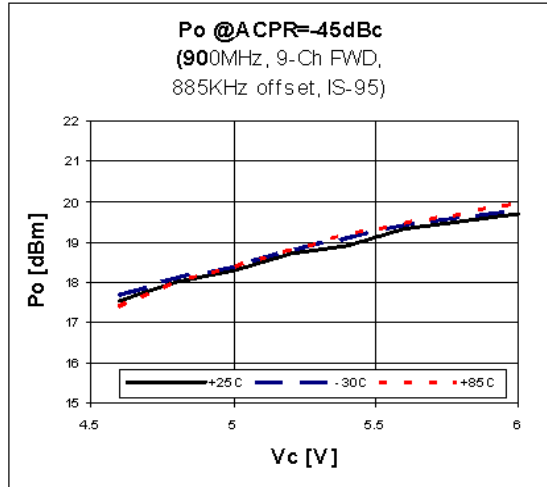
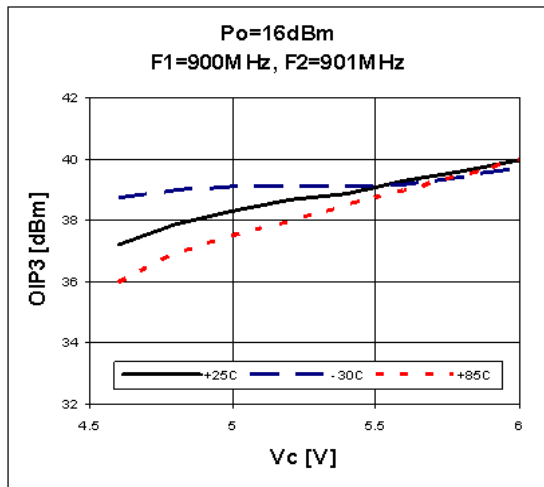
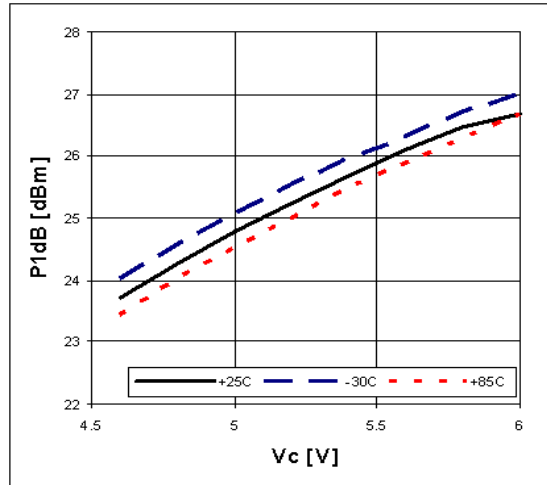
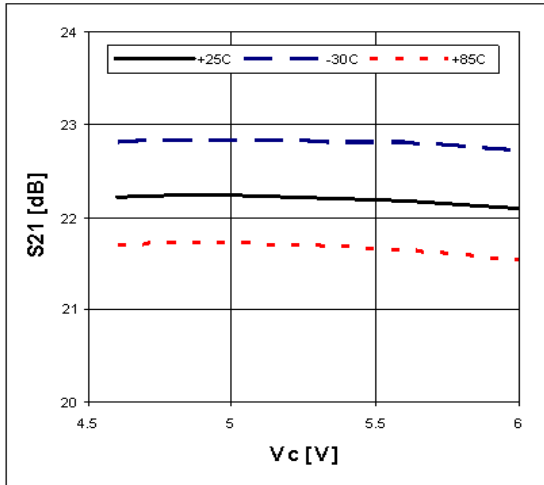
Schematic Diagram	BOM	Tolerance	
	C1	100pF	±5%
	C2	1000pF	±5%
	C3*	10uF	±20%
	C4	100pF	±5%
	C5	100pF	±5%
	C6	7pF	±5%
	C7	10pF	±5%
	L1	39nH	±5%
	L2	6.8nH	±5%

Note:
1. PCB: 31mil thick FR4.
2. Distance between the center of the shunt cap(C6) and the input pin of BT09VG _ <b><u>7.0mm.</u></b>
3. Distance between the center of the series cap(C7) and the output pin of BT09VG _ <b><u>3.5mm.</u></b>
4. Distance between the center of the shunt inductor(L2) and the output pin of BT09VG _ <b><u>5.5mm.</u></b>

**Typical Performance**  
 (Vc=5V, Ic=160mA, T=25°C)


### Performance Variation with Supply Voltage



### Application Circuit: 1900MHz

Schematic Diagram	BOM	Tolerance	
	C1	100pF	±5%
	C2	100pF	±5%
	C3*	10uF	±20%
	C4	100pF	±5%
	C5	100pF	±5%
	C6	4.7pF	±5%
	C7	2.7pF	±5%
	C8	1.5pF	±5%
L1	39nH	±5%	
L2	1nH	±2%	

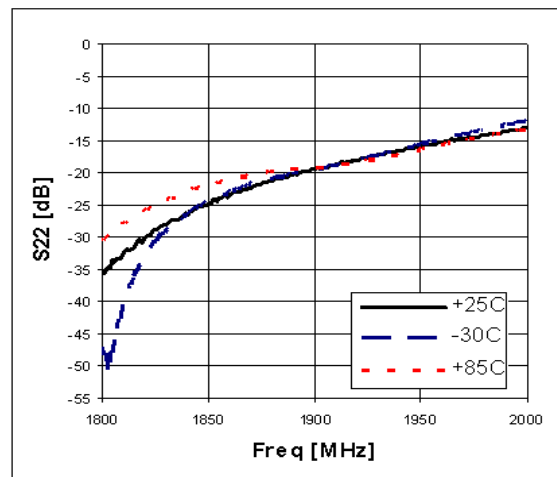
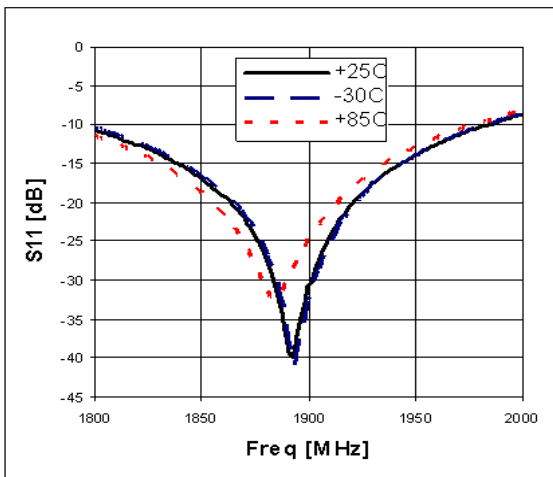
  

Note:1. PCB: 31mil thick FR4.

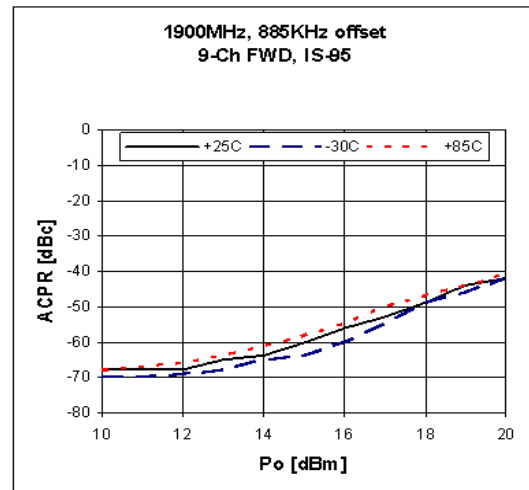
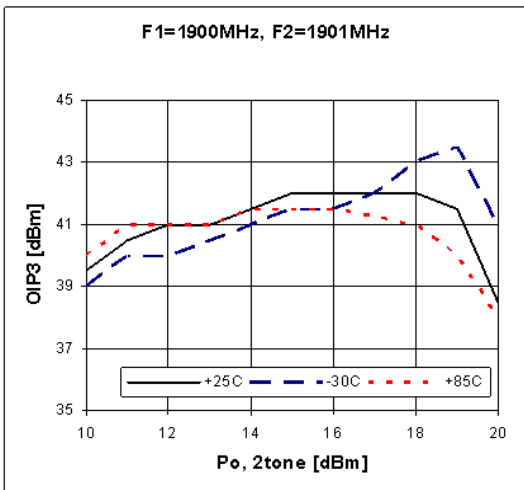
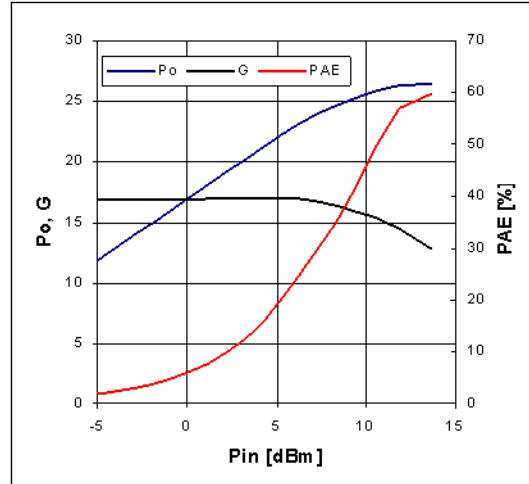
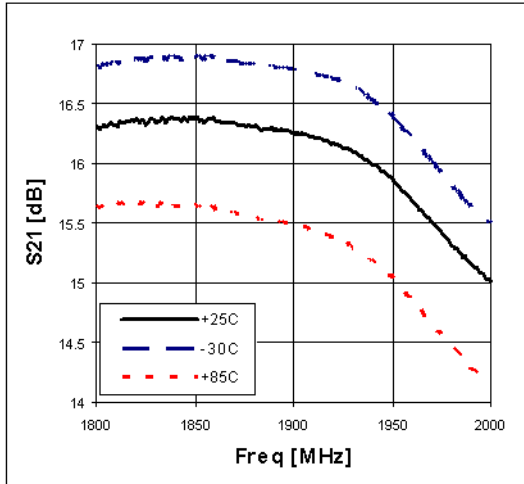
- Distance between the center of the series cap(C8) and the input pin of BT09VG **2.5mm.**
- Distance between the center of the shunt cap(C6) and the input pin of BT09VG **4.0mm.**
- Distance between the center of the series inductor (L2) and the output pin of BT09VG **3.5mm.**
- Distance between the center of the shunt cap(C7) and the output pin of BT09VG **8.0mm.**

\*Skipping C3 reduces device ruggedness.

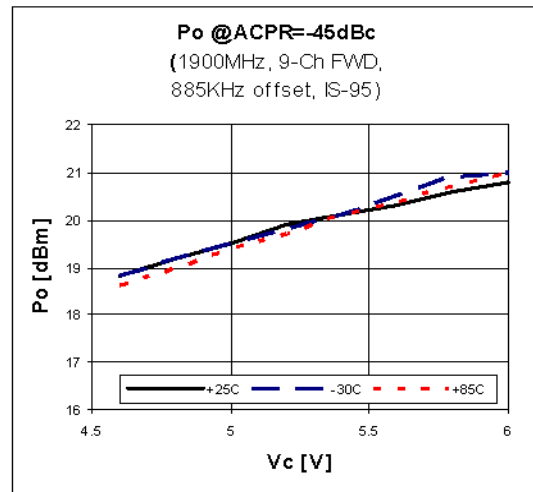
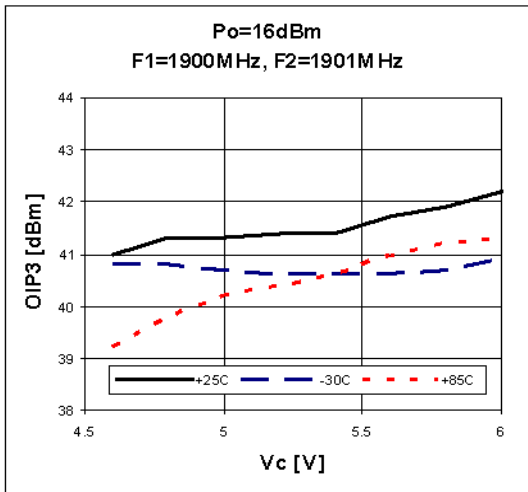
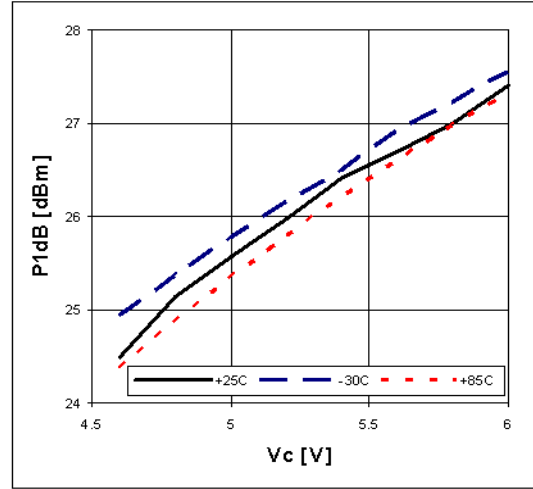
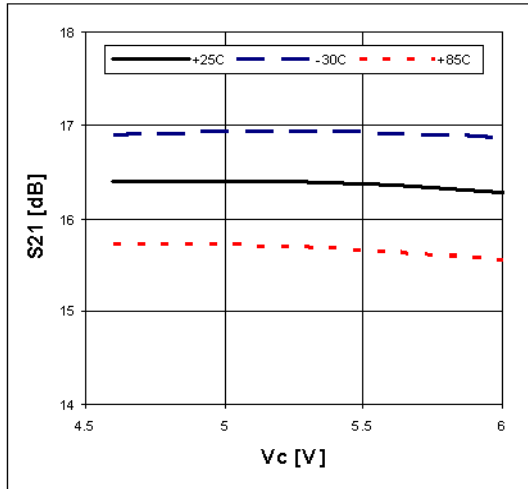
### Typical Performance (Vc=5V, Ic=160mA, T=25°C)





**5-4000 MHz Wideband Medium Power Amplifier**


### Performance Variation with Supply Voltage



### Application Circuit: 2450MHz

Schematic Diagram		BOM	Tolerance	
		C1	100pF	±5%
		C2	1000pF	±5%
		C3*	10uF	±20%
		C4	56pF	±5%
		C5	56pF	±5%
		C6	2.2pF	±5%
		C7	1.5pF	±5%
		C8	0.75pF	±5%
		L1	33nH	±5%

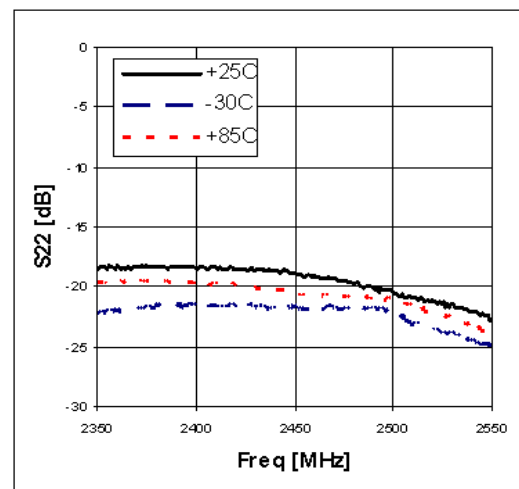
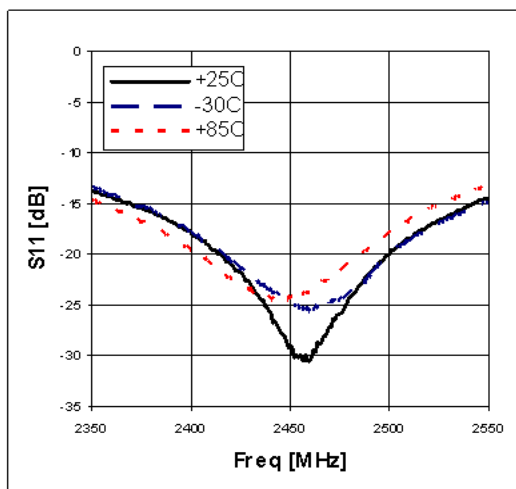
  

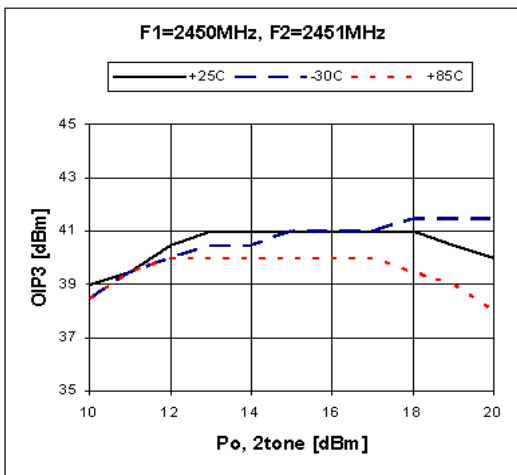
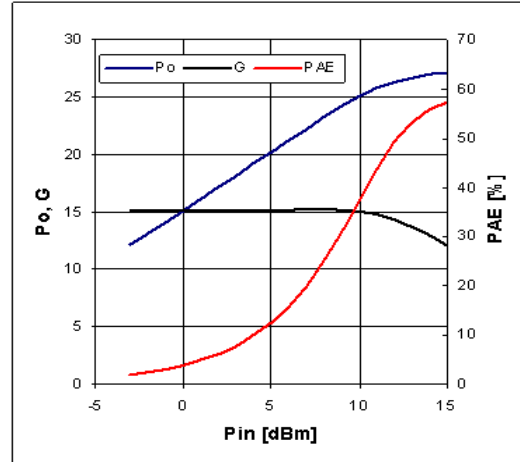
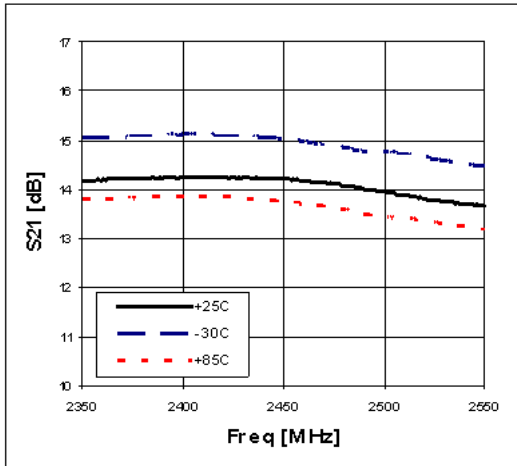
Note:	
1.	PCB: 31mil thick FR4.
2.	Distance between the center of the series cap(C8) and the input pin of BT09VG _ <b><u>2.5mm.</u></b>
3.	Distance between the center of the shunt cap(C6) and the input pin of BT09VG _ <b><u>4.0mm.</u></b>
4.	Distance between the center of the shunt cap(C7) and the output pin of BT09VG _ <b><u>6.2mm.</u></b>

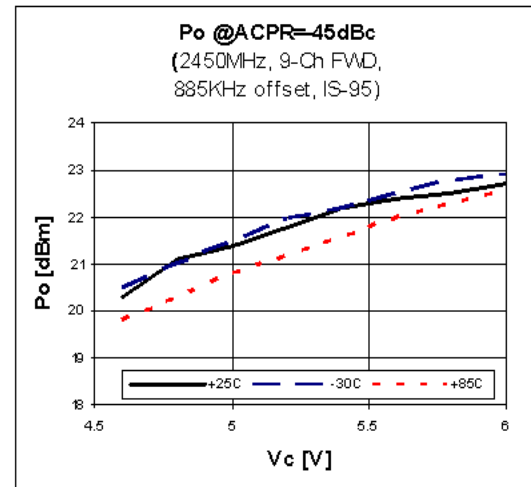
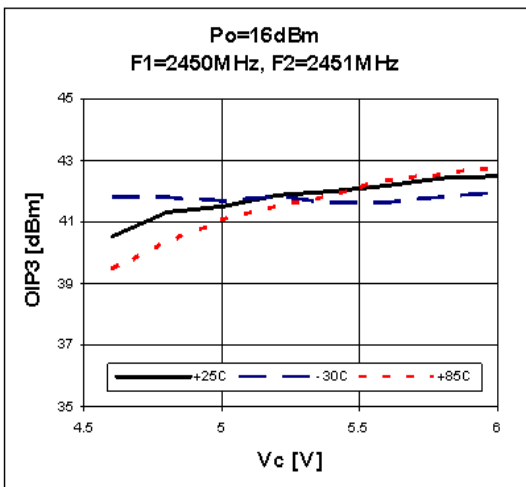
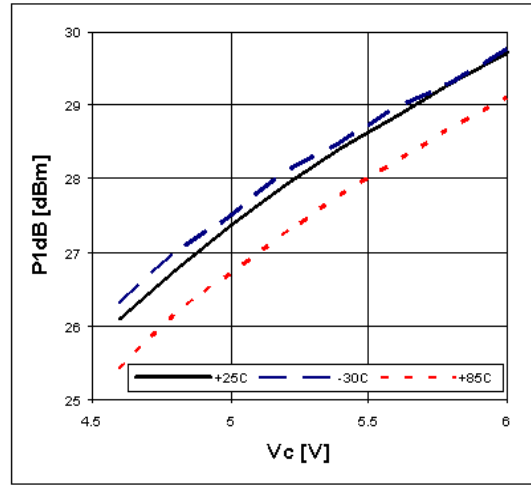
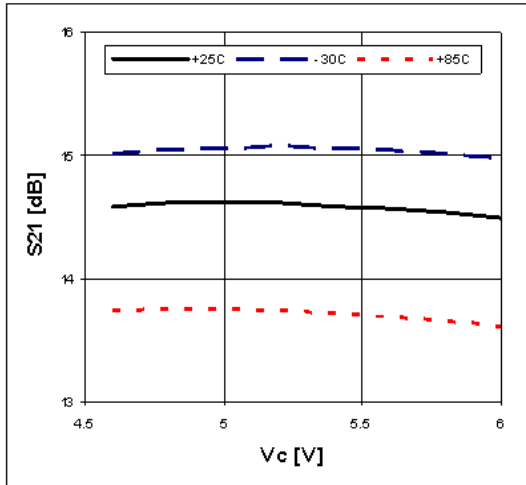
\*Skipping C3 reduces device ruggedness.

### Typical Performance (Vc=5V, Ic=160mA, T=25°C)





### Performance Variation with Supply Voltage



### Application Circuit: 3500MHz

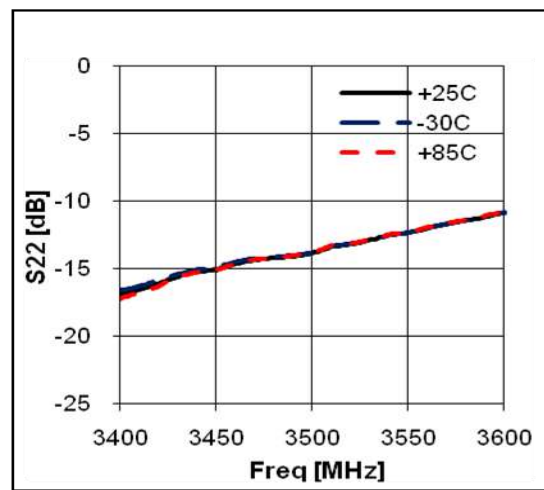
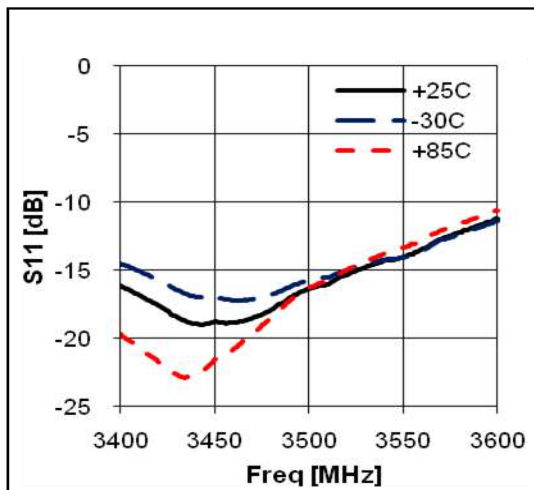
Schematic Diagram	BOM	Tolerance	
	C1	100pF	±5%
	C2	1000pF	±5%
	C3	10uF	±20%
	C4	22pF	±5%
	C5	22pF	±5%
	C6	0.5pF	±5%
	C7	0.5pF	±5%
L1	33nH	±5%	

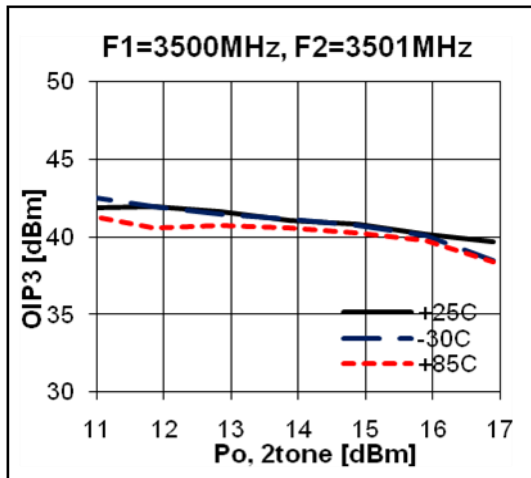
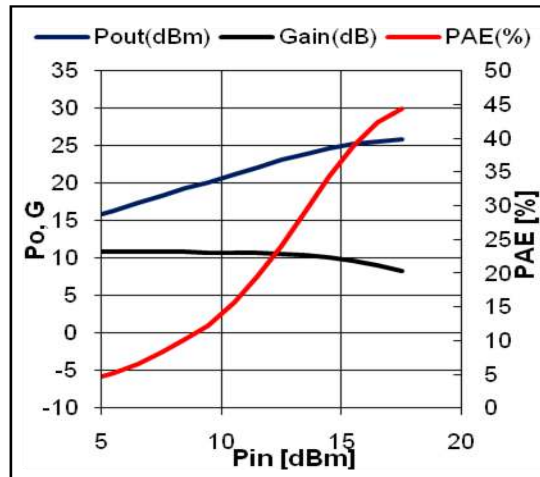
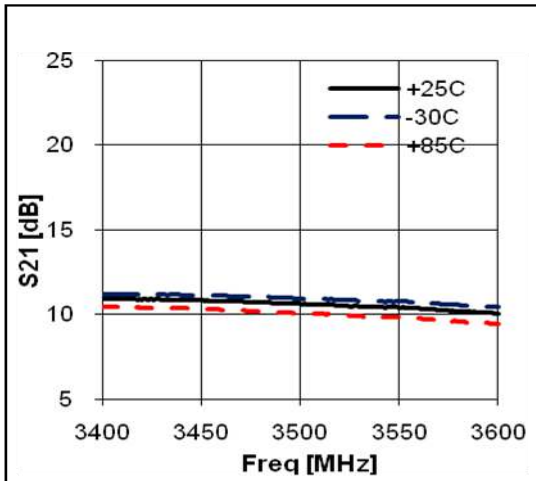
  

Note:

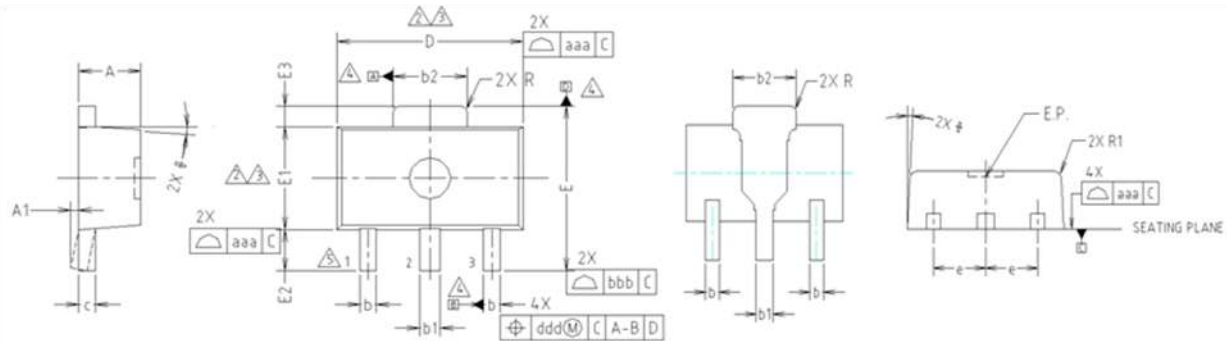
1. PCB: 31mil thick FR4.
2. Distance between the center of the series cap(C7) and the input pin of BT09VG \_ **2.5mm**.
3. Distance between the center of the shunt cap(C6) and the input pin of BT09VG \_ **8.5mm**.

### Typical Performance (Vc=5V, Ic=160mA, T=25°C)





### Package Outline Dimension

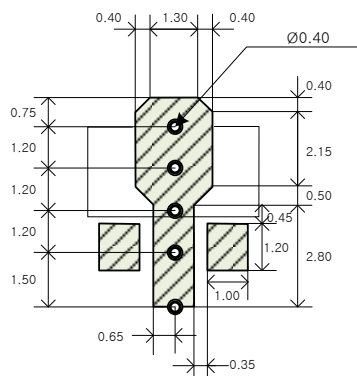


- NOTE:**  
1. DIMENSIONS IN MILLIMETERS.
- ⚠ DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.5mm PER END. DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.5mm PER SIDE.
  - ⚠ DIMENSIONS D AND E1 ARE DETERMINED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
  - ⚠ DATUMS A, B AND D TO BE DETERMINED 0.18mm FROM THE LEAD TIP.
  - ⚠ TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

SYMBOL	MILLIMETERS			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	1.40	1.50	1.60	
A1	0.00	—	0.10	
b	0.38	0.42	0.48	
b1	0.48	0.52	0.58	
b2	1.79	1.82	1.87	
c	0.40	0.42	0.46	
D	4.40	4.50	4.70	2,3
E	3.70	4.00	4.30	
E1	2.40	2.50	2.70	2,3
E2	0.80	1.00	1.20	
E3	0.40	0.50	0.60	
e	1.50 TYP.			
φ	4° TYP.			
R	0.15 TYP.			
R1	—	—	0.20	
SYMBOL	TOLERANCES OF FORM AND POSITION		NOTE	
aaa	0.15			
bbb	0.20			
ccc	0.10			
ddd	0.10			

### Suggested PCB Land Pattern and PAD Layout

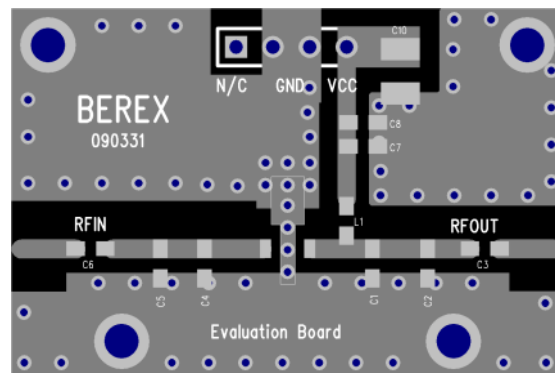
**PCB Land Pattern**



Note : All dimension are in millimeters

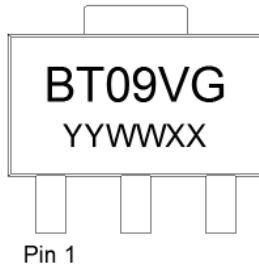
PCB lay out \_ on BeRex website

**PCB Mounting**





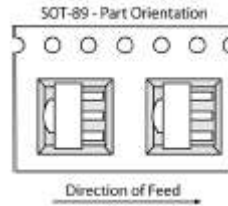
### Package Marking



YY = Year, WW = Working Week,  
XX = Wafer No.

### Tape & Reel

SOT89



Packaging information:

Tape Width (mm): 12  
Reel Size (inches): 7  
Device Cavity Pitch (mm): 8  
Devices Per Reel: 1000

### Lead plating finish

100% Tin Matte finish

(All BeRex products undergoes a 1 hour, 150 degree C, Anneal bake to eliminate thin whisker growth concerns.)

### MSL / ESD Rating

<b>ESD Rating:</b>	Class 1B
<b>Value:</b>	<b>Passes &lt;1000V</b>
<b>Test:</b>	Human Body Model (HBM)
<b>Standard:</b>	JEDEC Standard JESD22-A114
<b>MSL Rating:</b>	<b>Level 1 at +260°C convection reflow</b>
<b>Standard:</b>	JEDEC Standard J-STD-020



Proper ESD procedures should be followed when handling this device.

**RoHS Compliance**

This part is compliant with Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment (RoHS) Directive 2011/65/EU as amended by Directive 2015/863/EU.

This product also is compliant with a concentration of the Substances of Very High Concern (SVHC) candidate list which are contained in a quantity of less than 0.1%(w/w) in each components of a product and/or its packaging placed on the European Community market by the BeRex and Suppliers.

**NATO CAGE code:**

2	N	9	6	F
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